

Si PIN photodiode

S13954-01CT

High-speed response and wide temperature range

The S13954-01CT is a photodiode that has an extremely wide operating and storage temperature range (-40 to +125 °C). A highspeed response (230 MHz typ.) is achieved.

Features

- **→** High-speed response: 230 MHz (VR=3 V, RL=50 Ω , λ =650 nm, -3 dB)
- → Operating/storage temperature: -40 to +125 °C
- → Surface mount type, small and thin leadless package
- → Photosensitive area: φ1.5 mm
- **→** Suitable for lead-free solder reflow

Applications

→ Laser power monitoring, etc.

Structure

Parameter	Value	Unit
Photosensitive area	φ1.5	mm
Package	Epoxy/Glass	-
Window material	Silicone resin	-

- Absolute maximum ratings

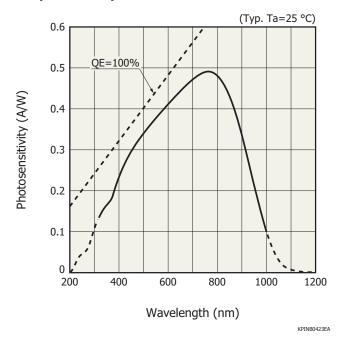
Parameter	Symbol	Value	Unit
Reverse voltage	VR max.	10	V
Operating temperature	Topr	-40 to +125	°C
Storage temperature	Tstg	-40 to +125	°C
Reflow soldering conditions*1	Tsol	Peak temperature: 260 °C, twice (see P.5)	-

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

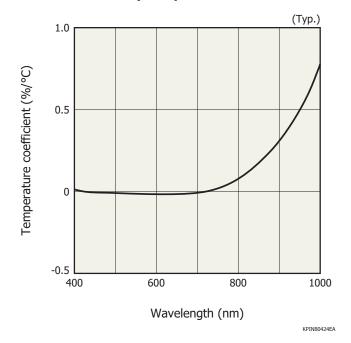
■ Electrical and optical characterisitcs (Ta=25 °C)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Spectral response range	λ		-	320 to 1000	-	nm
Peak sensitivity wavelength	λр		-	780	-	nm
Photosensitivity	S	λ=λρ	0.4	0.5	-	A/W
Dark current	ID	VR=3 V	-	0.01	1	nA
Temperature coefficient of ID	TCID	VR=3 V	-	1.12	-	times/°C
Cutoff frequency	tr	VR=3 V, RL=50 Ω λ =650 nm, -3 dB	125	230	-	MHz
Terminal capacitance	Ct	VR=3 V, f=1 MHz	-	13	25	pF

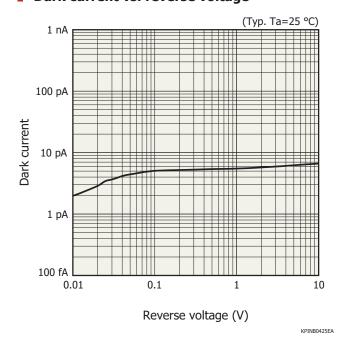
Spectral response



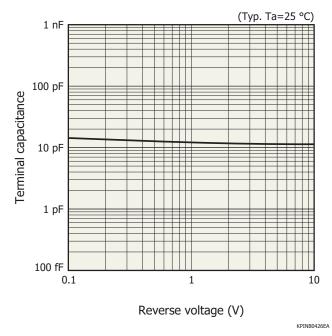
Photosensitivity temperature characteristics



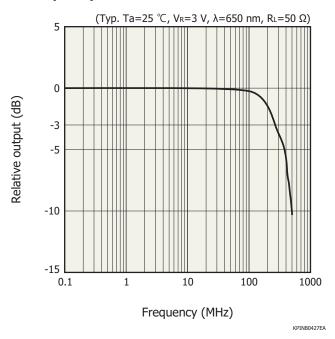
₽ Dark current vs. reverse voltage



Terminal capacitance vs. reverse voltage

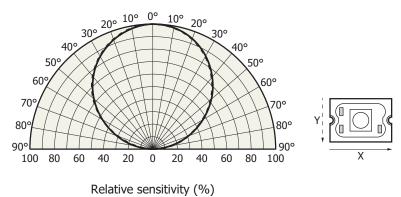


Frequency characteristics



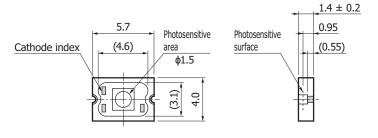
Directivity

(Typ. Ta=25 °C, light source: tungsten lamp)

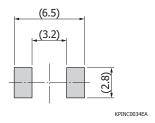


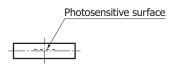
KPINB0428EA

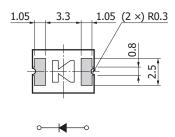
Dimensional outline (unit: mm)



- Recommended land pattern







Tolerance unless otherwise noted: ± 0.15 , $\pm 2^{\circ}$ Chip position accuracy with respect to package center X, Y ≤ 0.2 , $\theta \leq \pm 2^{\circ}$

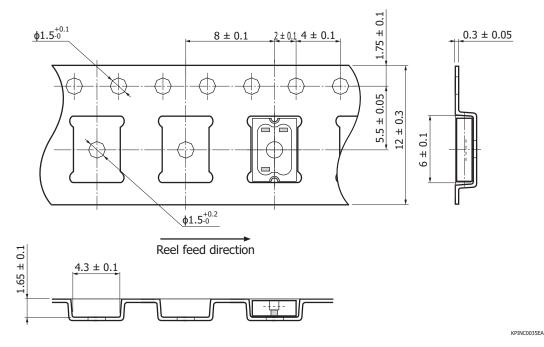
KPINA0123EA

Standard packing specifications

■ Reel (conforms to JEITA ET-7200)

Dimensions	Hub diameter	Tape width	Material	Electrostatic characteristics
254 mm	100 mm	12 mm	Polystyrene	Conductive

■ Embossed tape (unit: mm, material: polystyrene, conductive)

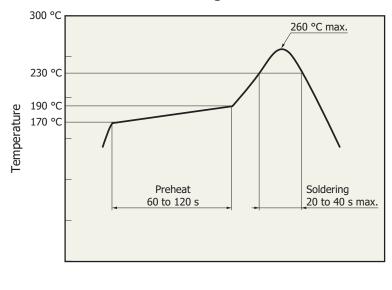


■ Packing quantity 2000 pcs/reel

Packing typeReel and desiccant in moisture-proof packaging (vacuum-sealed)



Recommended reflow soldering conditions



Time

KPINB0385EB

- · This product supports lead-free soldering. After unpacking, store it in an environment at a temperature of 30 °C or less and a humidity of 60% or less, and perform soldering within 72 hours.
- · The effect that the product receives during reflow soldering varies depending on the circuit board and reflow oven that are used. Before actual reflow soldering, check for any problems by tesiting out the reflow soldering methods in advance.

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
- Disclaimer
- · Surface mount type products
- Technical information
- · Si photodiode / Application circuit examples

Information described in this material is current as of February 2020.

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